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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Sheet	1	of	1	Application Number	10/692,649
				Filing Date	October 23, 2003
				First Named Inventor	Hossick-Schott
				Group Art Unit	3729
				Examiner Name	Tai V. Nguyen
				Attorney Docket Number	

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate, title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T2
NH	1	POWER GEOMETRY AND STRUCTURAL DESIGN OF THE HIGH VOLUMETRIC EFFICIENCY TANTALUM ELECTROLYTIC CAPACITOR-IEEE TRANSACTIONS ON PARTS, HYBRIDS, AND PACKAGING, VOL. PHP-9, NO. 3, SEPTEMBER 1793-STEPHEN E. HLUCHAN	
	2	APPROACHING THE LIMITS: THE LATEST DEVELOPMENTS IN SOLID TANTALUM CAPACITORS-ELECTRONIC ENGINEERING OCTOBER 1991-BILL MILLMAN	
	3	CARTS '98 PROGRAM-LOWEST ESR TANTALUM CHIP CAPACITOR, ERIC K. REED, JIM C. MARSHALL, JOHN D. PRYMAK	
	4	CARTS-EUROPE '98-LOWEST ESR TANTALUM CHIP CAPACITOR, ERIC K. REED, JIM C. MARSHALL, JOHN D. PRYMAK	
	5	CARTS '99-18 MILLIOHMS AND FALLING-NEW ULTRA-LOW ESR TANTALUM CHIP CAPACITORS, ERIC K. REED, JIM C. MARSHALL	
	6	CARTS-EUROPE '99-LOWEST AVAILABLE ESR CONFORMALLY-COATED MULTIPLE-ANODE TANTALUM CAPACITOR- JEREMY LADD, VISHAY SPRAGUE	
	7	CARTS-EUROPE 2001-IMPROVED ESR ON MnO ₂ TANTALUM CAPACITORS AT WIDE VOLTAGE RANGE-I. HORACEK, T. ZEDNICEK, M. KOMAREK, J. TOMASO, S. ZEDNICEK, W. A. MILLMAN, J. SIKULA, J. HLAVKA	
NH	8	CARTS 2002-LOWEST ESR TANTALUM CAPACITORS WITH HIGH CV VALUES-H. ZILLGEN, V. DÖGE, W. BRAUNWARTH	

Examiner Signature		Date Considered	1/3/08
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Unique citation designation number. 2 Applicant is to place a check mark here if English Translation is attached.

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